MRF10031

Microwave Power Silicon NPN Transistor
30W (peak), 960–1215MHz, 36V

Rev. V1

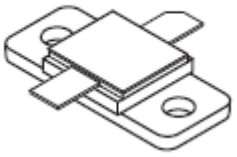
Features

- Guaranteed performance @ 960-1215MHz, 36Vdc
- Output power: 30W peak
- Minimum gain: 9.0dB min., 9.5dB typ.
- 100% tested for load mismatch at all phase angles with 10:1 VSWR
- Hermetically sealed, industry standard package
- Silicon nitride passivated
- Gold metallized, emitter ballasted for long life and resistance to metal migration
- Internal input matching for broadband operation

Description and Applications

Designed for 960–1215 MHz long or short pulse common base amplifier applications such as JTIDS and Mode–S transmitters.

Product Image



CASE 332A–03, STYLE 2

Maximum Ratings

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CES}	55	Vdc
Collector–Base Voltage (1)	V_{CBO}	55	Vdc
Emitter–Base Voltage	V_{EBO}	3.5	Vdc
Collector Current — Continuous (1)	I_C	3.0	Adc
Total Device Dissipation @ T_C = 25°C (1), (2) Derate above 25°C	P_D	110 0.625	Watts mW/°C
Storage Temperature Range	T_{stg}	– 65 to + 200	°C
Junction Temperature	T_J	200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (3)	$R_{\theta JC}$	1.6	°C/W

NOTES:
1. Under pulse RF operating conditions.
2. These devices are designed for RF operation. The total device dissipation rating applies only when the devices are operated as pulsed RF amplifiers.
3. Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques. (Worst case θ_{JC} value measured @ 23% duty cycle)

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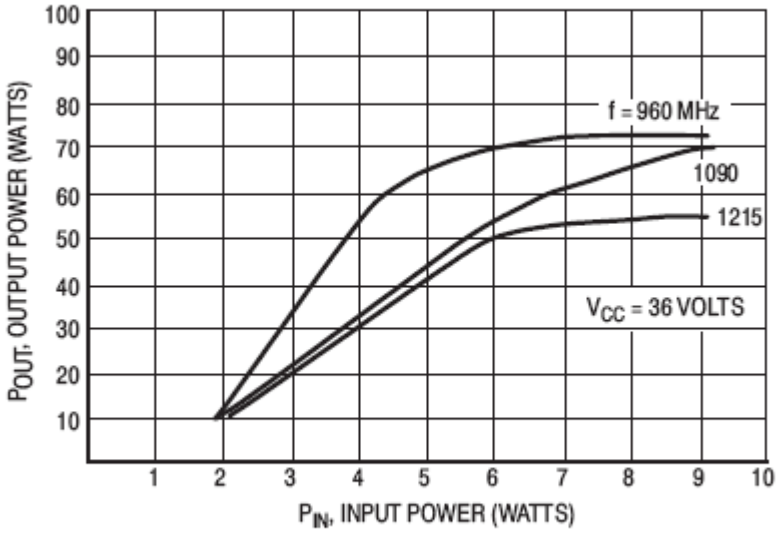
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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I_C = 25 mAdc, V_{BE} = 0)	$V_{(BR)CES}$	55	—	—	Vdc
Collector–Base Breakdown Voltage (I_C = 25 mAdc, I_E = 0)	$V_{(BR)CBO}$	55	—	—	Vdc
Emitter–Base Breakdown Voltage (I_E = 5.0 mAdc, I_C = 0)	$V_{(BR)EBO}$	3.5	—	—	Vdc
Collector Cutoff Current (V_{CB} = 36 Vdc, I_E = 0)	I_{CBO}	—	—	2.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I_C = 500 mAdc, V_{CE} = 5.0 Vdc)	h_{FE}	20	—	—	—
FUNCTIONAL TESTS (10 µs Pulses @ 50% duty cycle for 3.5 ms; overall duty cycle – 25%)					
Common–Base Amplifier Power Gain (V_{CC} = 36 Vdc, P_{out} = 30 W Peak, f = 960 MHz)	G_{PB}	9.0	9.5	—	dB
Collector Efficiency (V_{CC} = 36 Vdc, P_{out} = 30 W Peak, f = 960 MHz)	η	40	45	—	%
Load Mismatch (V_{CC} = 36 Vdc, P_{out} = 30 W Peak, f = 960 MHz, VSWR = 10:1 All Phase Angles)	ψ	No Degradation in Output Power			



Output power versus input power

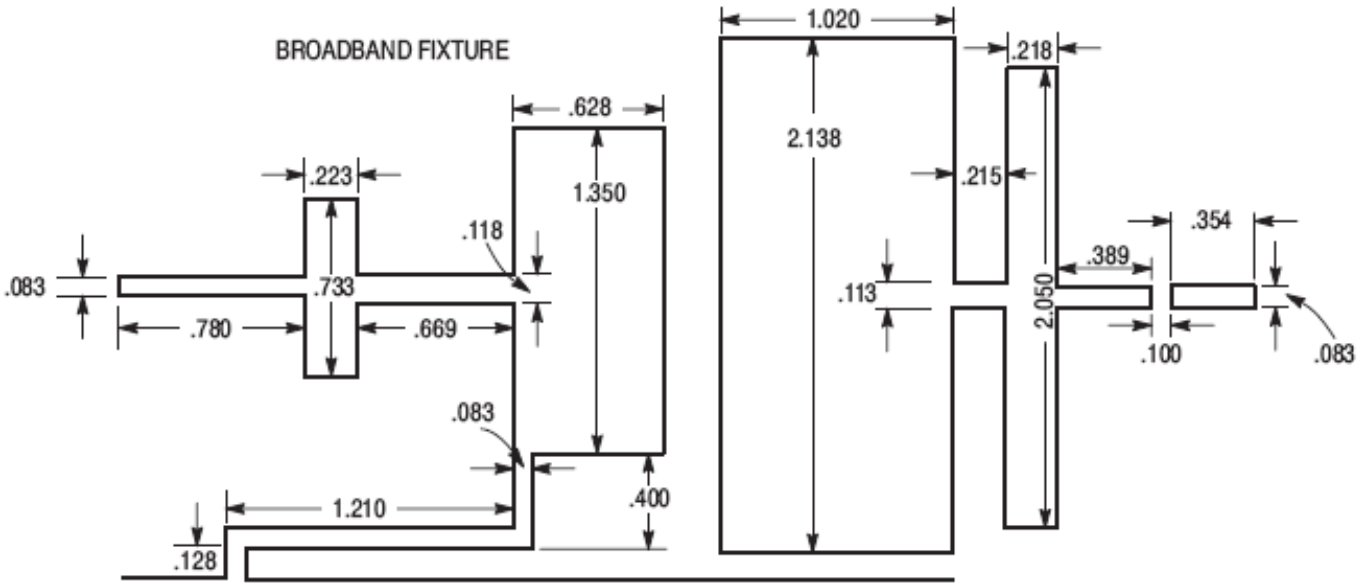
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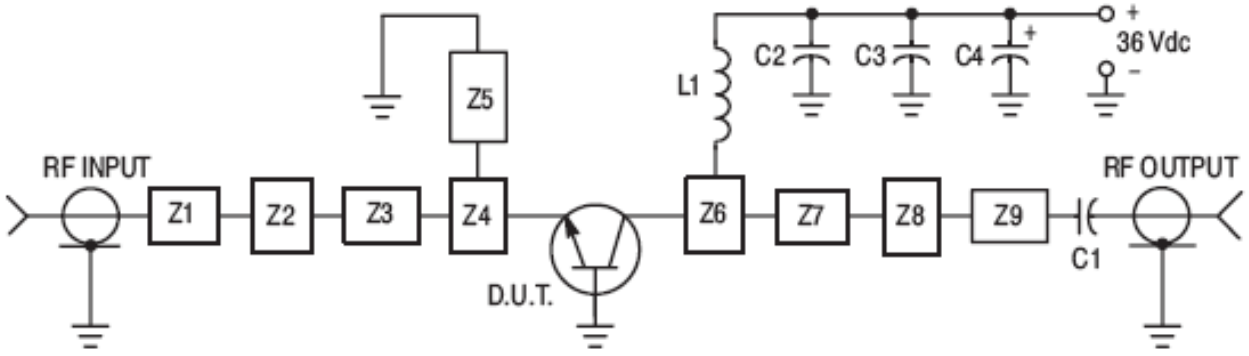
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C1 — 75 pF 100 Mil Chip Capacitor
C2 — 39 pF 100 Mil Chip Capacitor
C3 — 0.1 µF
C4 — 1000 µF, 50 Vdc, Electrolytic
L1 — 3 Turns #18 AWG, 1/8″ ID, 0.18 Long

Z1–Z9 — Microstrip, See Details
Board Material — Teflon, Glass Laminate
Dielectric Thickness = 0.030″
ε_r = 2.55, 2 Oz. Copper

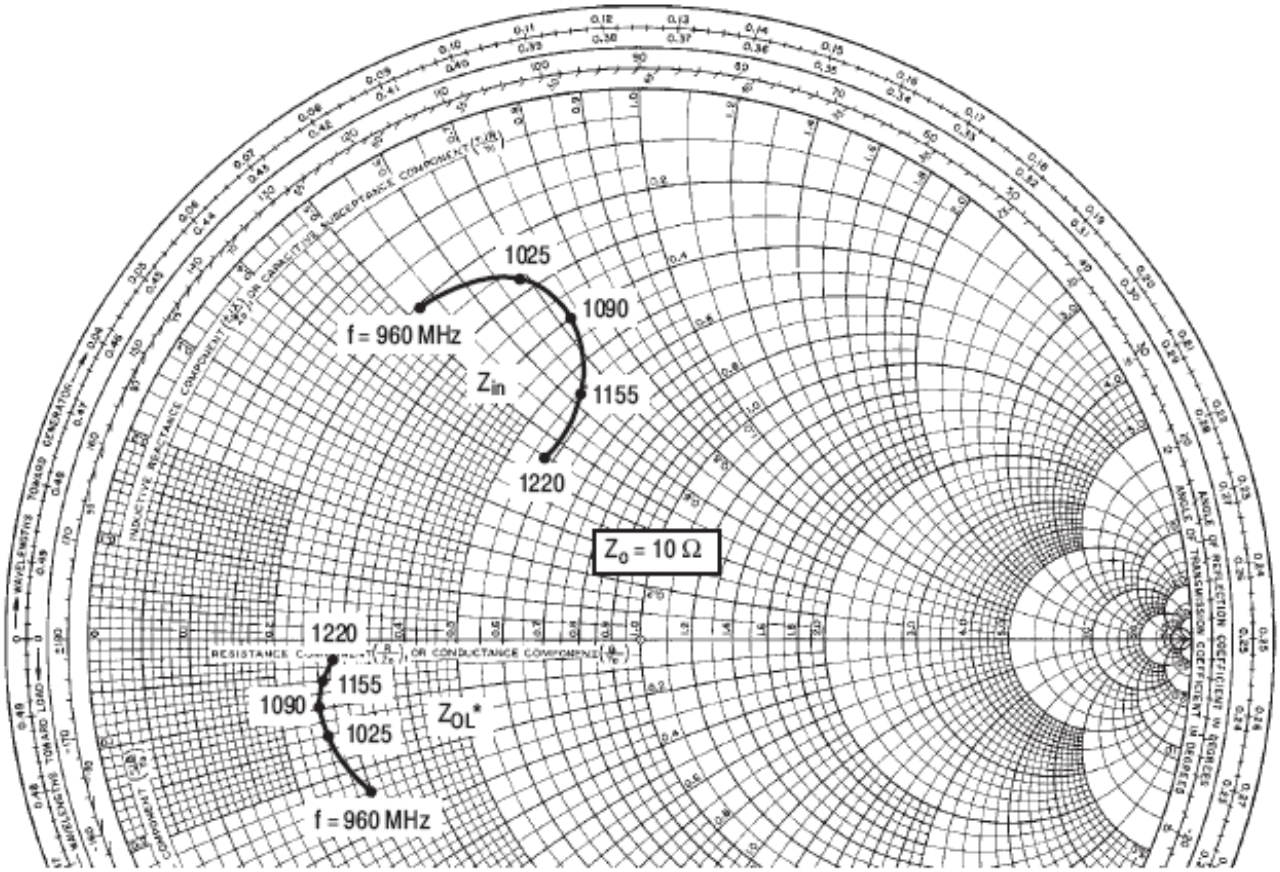
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P_{out} = 30 W Pk V_{CC} = 36 V

f MHz	Zin Ohms	Z_{OL}* Ohms
960	2.05 + j5.2	2.9 – j2.35
1025	2.67 + j6.34	2.55 – j1.3
1090	4.0 + j7.1	2.52 – j0.9
1155	5.5 + j6.2	2.6 – j0.6
1220	5.7 + j4.3	2.8 – j0.3

Z_{OL}* = Conjugate of the optimum load impedance into which the device operates at a given output power, voltage, and frequency.

Series equivalent input/output impedances

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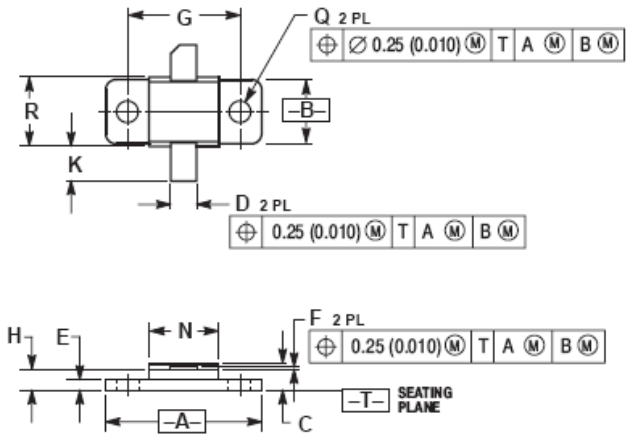
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PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.890	0.910	22.61	23.11
B	0.370	0.400	9.40	10.16
C	0.145	0.160	3.69	4.06
D	0.140	0.160	3.56	4.06
E	0.055	0.065	1.40	1.65
F	0.003	0.006	0.08	0.15
G	0.650 BSC		16.51 BSC	
H	0.110	0.130	2.80	3.30
K	0.180	0.220	4.57	5.59
N	0.390	0.410	9.91	10.41
Q	0.115	0.135	2.93	3.42
R	0.390	0.140	9.91	10.41

STYLE 1:
PIN 1. COLLECTOR
2. EMITTER
3. BASE

CASE 376B–02
ISSUE B

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